

9097250 TOSHIBA (DISCRETE/OPTO)

67C 09141

D T-27-01

» MOS FET «

Type No.		VDS (V)	ID (mA)	PD (mW)	IDSS			IYfsI TYP.			Crss MAX.			NF MAX.			
					VDS (V)	ID (mA)	VGS (V)	VDS (V)	ID (mA)	VGS (V)	VDS (V)	ID (mA)	f (MHz)	VDS (V)	ID (mA)	f (Hz)	RS (Ω)
N-Channel	P-channel																
2SK241		20	30	200	1.5~14	10	0	10	10	10	10	0.05	10	1	3.0	10	—

Application

VHF Amp FM RF
(Cascode Type)3. μ -X PACKAGE SERIES

» GaAs MES FET «

Type No.	IDSS		PD	VDS	ID	VDS	IYfsI (1KHz) TYP.		NF TYP.	
	N-Channel	P-Channel	(mW)	(V)	(mA)	(V)	VDS	VG2S	VDS	F
3SK121			20~45	5	50	10	(mS)	(V)	(dB)	(MHz)

Application

UHF RF

» TRANSISTOR «

Type No.	hFE		PC	VCEO	IC	VCE	fT TYP. (MIN.)		NF MAX. (TYP.)	
	NPN	PNP	(mW)	(V)	(mA)	(V)	VCE	IC	VCC	VAGC
2SC2804			200	20	20	10	900	2	12	3
2SC2805			200	15	50	3	1500	8	—	—
2SC2806			200	15	50	3	(600)	8	—	—
2SC2876			200	7.5	80	3	7000	5	5	—
2SC3137			200	15	50	10	2400	2	10	—
2SC3172			200	20	50	10	1400	5	12	—
2SC3302			200	12	70	10	5000	20	10	—
2SC3548			200	15	30	10	4000	10	10	—
2SC3602			200	20	20	10	1100	2	12	3
2SC3608			200	12	80	10	7000	20	10	5

Application

UHF RF Amp

UHF OSC. VHF MIX

VHF OSC.

VHF~C Band Low Noise
Amp

UHF MIX OSC

VHF MIX

VHF/UHF Low Noise
Amp

UHF OSC (NEW)

UHF RF (NEW)

VHF/UHF Low Noise
Amp (NEW)

» MOS FET «

Type No.	IDSS		PD	VDS	ID	VDS	IYfsI (1KHz) TYP.		NF MAX. (TYP.)	
	N-Channel	P-Channel	(mW)	(V)	(mA)	(V)	VDS	VG2S	VDD	f
3SK101			200	20	30	15	20	4	15	200
3SK102			200	20	30	15	8 MIN.	4	15	800
3SK114			200	15	30	6	20	3	6	200
3SK115			200	15	30	6	17	3	6	800
3SK145			200	13.5	30	6	16	3	6	800

Application

VHF RF Amp

UHF RF Amp

VHF RF Amp

UHF RF Amp

UHF RF Amp (NEW)

O: 1.5~3.5 Y: 3~7 GR: 6~14

Y: 20~35 GR: 30~45

* Y: 3~7 GR: 6~14 BL: 12~24 ** O: 0~2 Y: 1~6

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